CV Sim: Simulation of the simple redox reaction (E)
Part II: The effect of the ohmic drop and the double layer capacitance

I – INTRODUCTION
In the part I, we described how and which kinetic information could be deduced from the analysis of the voltammetry curves obtained at various scan rates. This second part aims at illustrating the effect of ohmic drop and double layer capacitance on the general shape of an I vs. E curve. Similarly, to the first part of the note, the simplest case is described: a) the reaction is a simple redox reaction, b) only the oxidizing species is present in the solution, c) only a linear voltammetry is performed.

II – BACKGROUND
II - 1 THE DOUBLE LAYER CAPACITANCE
In a real electrochemical cell, the electrode-electrolyte surface behaves as a capacitance (Fig. 1). Consequently, the current response of an electrode undergoing a potential perturbation has two components: a Faradaic component, related to the actual electrochemical reaction and a capacitive component related to the discharge of the double layer capacitor. More information on the double layer capacitance are given in [1].

The total current I is:

\[ I = I_c + I_f \]  

where \( I_c \) is the capacitive current and \( I_f \) the Faradaic current.

\[ I_c = C_{dl} \left( \frac{dE}{dt} \right) = -C_{dl}v \]  

where \( C_{dl} \) is the double layer capacitance and \( v \) the constant scan rate. The minus sign is because the reduction reaction is being studied, hence the scan is performed from the standard potential to more negative values.

II - 2 THE ELECTROLYTE RESISTANCE AND THE OHMIC DROP
The electrolyte resistance \( R_\Omega \) between the working electrode and the reference electrode can create an ohmic drop \( IR_\Omega \) (Fig. 1). The consequence of this ohmic drop is that the potential \( E(t) \) actually seen by the working electrode is different from the applied potential \( V \) (Fig. 1).

If we consider the scan rate \( v \) constant with the time \( t \):

\[ E(t) = E_{init} + vt - I(t)R_\Omega \]  

with \( E_{init} \) the initial potential of the scan. It is possible in CV Sim to account for the presence of the electrolyte resistance and the double layer capacitance in the setup window as shown in Fig. 2.
III – EFFECT OF \( C_{dl} \)

The parameters are the following:

- \( k^o = 1 \text{ cm.s}^{-1} \)
- Initial \( C_A: 4 \times 10^{-4} \text{ mol.cm}^{-3} (4.10^{-1} \text{ mol.L}^{-1}) \) and initial \( C_B: 0 \)
- \( D_A = D_B = 10^{-6} \text{ cm}^2 \cdot \text{s}^{-1} \)
- \( A = 0.03142 \text{ cm}^2 \) (linear semi-infinite electrode)
- \( E_{\text{init}} = E^o + 0.3 \text{ V} \)
- \( E_1 = -0.3 \text{ V} \)

A “random” \( k^o \) and a scan rate of 10 V/s were used. The effect of a 100 µF double layer capacitance can be seen on a \( I \) vs. \( E \) curve in Fig. 3a. (with \( R_\Omega = 0 \)) The total current is shifted to a lower values.

As the scan rate is constant, the contribution of the double layer capacitance on the total current is also constant, as described by Eqs. 1 and 2. The capacitive current can be seen in Fig. 3b (green curve). In this case, the capacitive current is lower than the Faradaic peak current. If the scan rate increases the capacitive current becomes much more important and can reach higher values than the Faradaic current as can be seen in Fig. 4. The constant capacitive is equal to -100 mA with a peak current of -180 mA.

Note that CV Sim allows the user to plot the total current \( I \), the capacitive current \( I_c \) and the Faradaic current \( I_f \) (File Selection window).

IV – EFFECT OF \( R_\Omega \)

The same conditions as the preceding simulations were used except that \( C_{dl} \) was set to 0. Fig. 5 shows the \( I \) vs. \( E \) curve of a system with three different \( R_\Omega \). The effect of the electrolyte resistance is not as straightforward as the effect of the capacitance. As \( R_\Omega \) increases, both the peak potential and current (\( E_p \) and \( I_p \), respectively) are shifted: \( E_p \) to lower values and \( |I_p| \) to lower values.

In Fig. 5, what is shown is not \( E(t) \) (the potential seen by the electrode) but \( v_t \), the actual control potential ramp or in other terms the actual potential applied by the potentiostat. However, the current is the actual current response of the system to the
potential $E(t)$. The effect of the resistance is to slow down the scan rate as for each time step, the actual potential seen by the electrode is lower than the control potential. This can be seen in Fig. 6, where the true potential seen by the electrode is plotted as a function of time for three electrolyte resistances.

![Figure 6: Potential ramp seen by the electrode with three different electrolyte resistances: 0, 20 and 100 Ω (control scan rate of 10 V.s⁻¹).](image)

The potential seen by the electrode is not linear anymore when the electrolyte resistance is not negligible anymore. What can also be seen is that the end potential is increasing with the ohmic drop, which shows that the average scan rate decreases as the ohmic drop increases. It was shown in the first part of this note that for the two limiting cases of the (E) reaction, $I_p$ is proportional to the square root of the scan rate. If the scan rate is lower then the peak current is also lower. This explains why in Fig. 5, $|I_p|$ decreases as $R_Ω$ increases.

**V – COMBINED EFFECT OF $C_{dl}$ and $R_Ω$**

The total current $I$, the capacitive current $I_c$ and the Faradaic current $I_f$ can be seen in Fig. 7 for which an ohmic drop of 20 Ω and a capacitance of 100 µF were used. It can be seen that, contrary to Fig. 3b, the capacitive current is not constant with time. The capacitive current is related to the potential time variation $dE/dt$ (Eq. 2), which in this case is not a constant, as the ohmic drop creates a non-linear potential variation. In other terms, the expression $dE/dt$ in Eq. 2 is not equal to $\nu$ and is time-dependent.

The expression $dE/dt$ becomes:

$$\frac{dE}{dt} = \frac{d}{dt}(E_{ain} + \nu t - R_Ω I_p)$$

Considering a constant scan rate, it gives:

$$\frac{dE}{dt} = -\nu + R_Ω \frac{dl}{dt}$$

Inserting Eq. 5 in Eq. 2, we have a time-dependent expression of $I_c$:

$$I_c = -C_{dl} \left(\nu - R_Ω \frac{dl}{dt}\right)$$
Figure 7: a) $I$ vs. $t$ curve with $C_{dl} = 100 \, \mu F$ and $R_\Omega = 20$ Ohm Total current $I$, Faradaic current $I_f$ and capacitive current $I_c$. b) Inset of the total current at short times. The time constant $t_c$ and the capacitive current $I_c$ can be determined.

The system at short times ($\approx 0.01 \, s$) can be considered equivalent to an R+C circuit i.e. there is no Faradaic current. The current response of an R + C system to a constant potential ramp $v$ is:

$$I = vC_{dl} \left( 1 - \exp \left( -\frac{t}{R_\Omega C_{dl}} \right) \right)$$

(7)

The limit of this function at $t \to +\infty$ is $vC_{dl}$, which is the capacitive current $I_c$ (Fig. 7). The slope of this function around $t = 0$ (which is equal to the value at $t = 0$ of the time derivative of eq. 2) is $v/R_\Omega$. The equation of the function is $I(t) = vt/R_\Omega$.

VI - CONCLUSION

The effects of the ohmic drop and of the double layer capacitance on the shape of the $I$ vs. $E$ curve of a single electron redox reaction was studied using CV Sim. In absence of ohmic drop, the potential $E(t)$ seen by the electrode is the same as the control. The double layer capacitance only adds a constant capacitive current to the Faradaic current. The presence of an ohmic drop modifies the potential seen by the electrode, which is not a linear potential ramp anymore. In case of the presence of both an ohmic drop and a double layer capacitance, their values can be determined using the early current response. All these aspects can be simulated by CV Sim, which makes CV Sim a very useful tool for teaching purpose.

Data files can be found in:
C:\Users\xxx\Documents\EC-Lab\Data\Samples\Fundamental Electrochemistry\AN41_

REFERENCES

1. Application note #21 “Measurements of the double layer capacitance”

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